



浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO.,LTD.

产品规格书

Specification of products

产品名称：整流管模块

产品型号：MDC200A/3500V-Y05

浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO., LTD.

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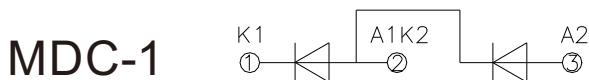
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拟制	审核	核准
林益龙	曹剑龙	宗瑞

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_j (°C)	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Single side cooled, $T_C=100^\circ\text{C}$	150			200	A
$I_{F(RMS)}$	RMS forward current	Single side cooled, $T_C=100^\circ\text{C}$	150			267	A
V_{RRM}	Repetitive peak reverse voltage	V_{RRM} tp=10ms $V_{RsM} = V_{DRM} \& V_{RRM} > 200\text{V}$	150	3500	3500		V
I_{RRM}	Repetitive peak current	at V_{RRM}	150			12	mA
I_{FSM}	Surge for ward current	10ms half sine wave	150			6.0	KA
I^2t	I^2T for fusing coordination	$V_R=0.6V_{RRM}$				106	$\text{A}^2\text{s} \times 10^3$
V_{FO}	Threshold voltage		150			0.80	V
r_F	Forward slop resistance					1.21	$\text{m}\Omega$
V_{FM}	Peak for ward voltage	$I_{FM}=600\text{A}$	25			1.40	V
$R_{th(j-c)}$	Thermal resistance Junction to heatsink	At 180° sine Single side cooled				0.100	$^\circ\text{C}/\text{W}$
V_{iso}	Isolation voltage	50Hz, RM. S,t=1min, $I_{iso} : 5\text{mA(max)}$		10000			V
F_m	Terminal connection torque(M10)				10.0		N.m
	Mounting torque(M6)				5.0		N.m
T_{Stg}	Stored temperature			-40		125	$^\circ\text{C}$
W_t	Weight				1410		g
Outline							

OUTLINE DRAWING & CIRCUIT DIAGRAM



Rating and Characteristic

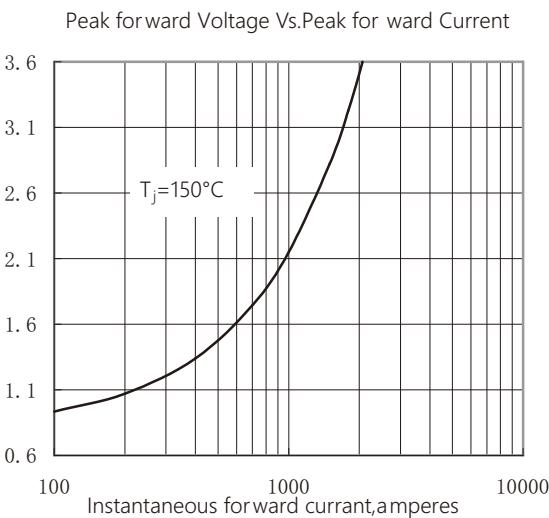


Fig.1

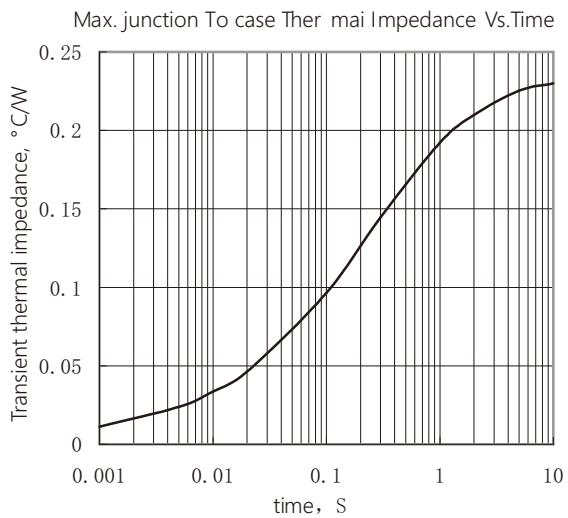


Fig.2

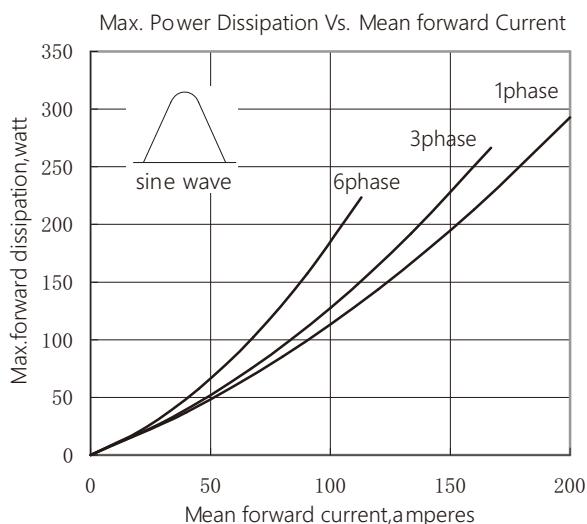


Fig.3

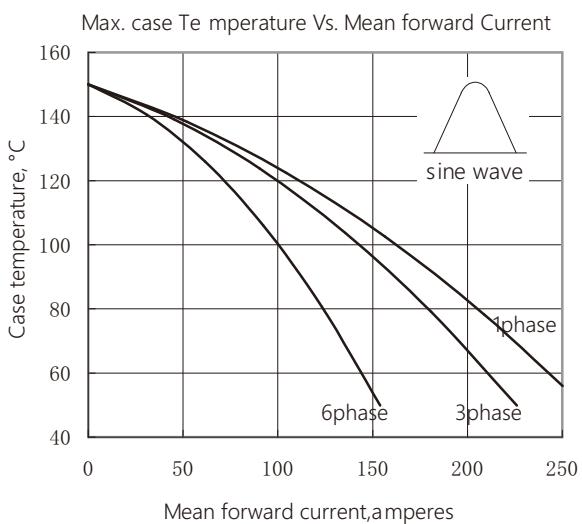


Fig.4

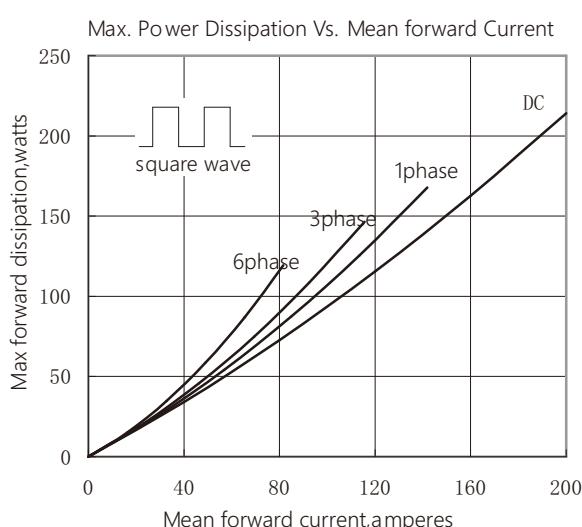


Fig.5

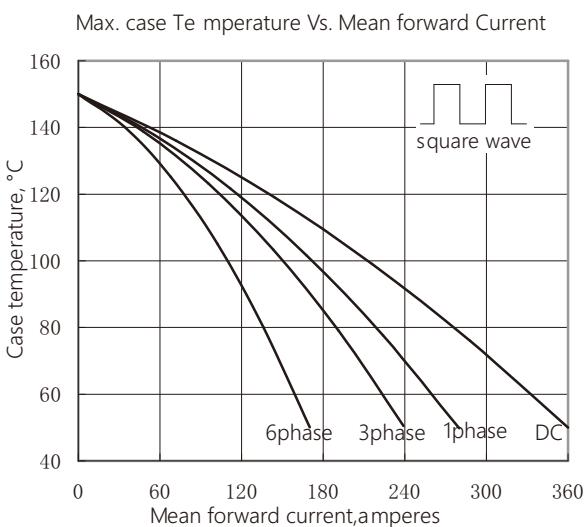


Fig.6

Outside Dimension

